IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicants: Application No.: Date Filed: Title:		BRAZIS ET AL	Group Art Unit: Examiner:				
		02/27/2004	Examiner.				
		ORGANIC SEMICONDU	ORGANIC SEMICONDUCTOR INVERTING CIRCUIT				
INFORMATION DISCLOSURE STATEMENT (IDS)							
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SIR:							
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III. 🔲	CROSS REFERENCE TO RELATED APPLICATION(S) The Examiner is advised that the following co-pending application(s) contain(s) subject matter that be related to the present application. By bringing this (these) applications to the Examiner's attendant(s) does(do) not waive the confidentiality provisions of 35 U.S.C. §122.			s to the Examiner's attention,			
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			References Foreign Search Report Other:	

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INFORMATION DISCLOSURE STATEMENT BY APPLICANT			JRE	Filing Date	02/27/2004	
			NT	First Named Inventor	BRAZIS ET AL	
				Group Art Unit		
(use as m	any sheets as necessary)		Examiner Name		
Sheet	1	of	1	Attorney Docket Number	CML01416T	

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Examiner Initials*					
		KNOBLOCH, A.; BERNDS, A.; CLEMENS, W. "PRINTED POLYMER TRANSISTERS" SIEMENS CORPORATE TECHNOLOGY, IEEE 2001, SECTION 4: POLYMER ELECTRONIC DEVICES II.			
		KLAUK, H.; GUNDLACH, D.; JACKSON, T. "FAST ORGANIC THIN FILM TRANSISTOR CIRCUITS" IEEE ELECTRON DEVICE LETTERS, VOLUME 20, NUMBER 6, PAGES 289-291, JUNE 1999			
		ULLMANN, A.; FLICKER, J.; FIX, W.; ROST, H.; CLEMENS, W.; "HIGH PERFORMANCE ORGANIC FILED- EFFECT TRANSISTORS AND INTEGRATED INVERTERS" MAT. REC. SOC. SYMP. PROC. VOL 665, 2001 MATERIAL RESEARCH SOCIETY.			
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